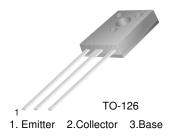


FJE3303 High Voltage Fast-Switching NPN Power Transistor

- High Voltage Capability
- · High Switching Speed
- · Suitable for Electronic Ballast and Switching Regulator



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units V			
V _{CBO}	Collector-Base Voltage	700				
V _{CEO}	Collector-Emitter Voltage	400 V				
V _{EBO}	Emitter-Base Voltage	9	V			
I _C	Collector Current (DC)	1.5	A			
I _{CP}	Collector Current (Pulse) *	3	A			
I _B	Base Current (DC)	0.75	A			
I _{BP}	Base Current (Pulse) *	1.5	A			
P _C	Collector Dissipation ($T_C = 25^{\circ}C$)	20	W			
TJ	Junction Temperature	150	°C			
T _{STG}	Storage Temperature	-65 ~ 150	°C			

* Pulse Test: Pulse Width = 5ms, Duty Cycle $\leq 10\%$

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units		
BV _{CBO}	Collector-Base Breakdwon Voltage	$I_{\rm C} = 500 \mu {\rm A}, \ I_{\rm E} = 0$	700			V		
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA, I _B = 0	400			V		
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 500μA, I _C = 0	$_{\rm E} = 500\mu A, I_{\rm C} = 0$ 9					
I _{CBO}	Collector Cut-off Current	V _{CB} = 700V, I _E = 0			10	μA		
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$	3 5 E					
h _{FE1} h _{FE2}	DC Current Gain *	$V_{CE} = 2V, I_{C} = 0.5A$ $V_{CE} = 2V, I_{C} = 1.0A$	8 5		21			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$\begin{split} I_{C} &= 0.5A, I_{B} = 0.1A \\ I_{C} &= 1.0A, I_{B} = 0.25A \\ I_{C} &= 1.5A, I_{B} = 0.5A \end{split}$			0.5 1.0 3.0	V V V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 0.5$ A, $I_{\rm B} = 0.1$ A $I_{\rm C} = 1.0$ A, $I_{\rm B} = 0.25$ A			1.0 1.2	V V		
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.1A$	4			MHz		
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 0.1MHz		21		pF		
t _{ON}	Turn On Time	V _{CC} = 125V, I _C = 1A			1.1	μs		
t _{STG}	Storge Time	$I_{B1} = 0.2A, I_{B2} = -0.2A$			4.0	μs		
t _F	Fall Time	$-R_{L} = 125\Omega$			0.7	μs		

Electrical Characteristics T_c = 25°C unless otherwise noted

* Pulse Test: PW \leq 300 $\mu s,$ Duty Cycle \leq 2%

h_{FE} Classification

Classification	H1	H2
h _{FE1}	8 ~ 16	14 ~ 21



Typical Performance Characteristics

Figure 1. Static Characteristic

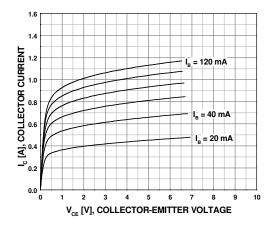


Figure 3. Collector-Emitter Saturation Voltage

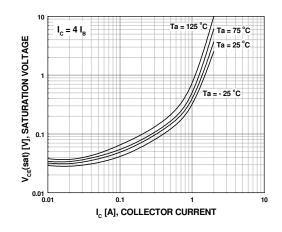
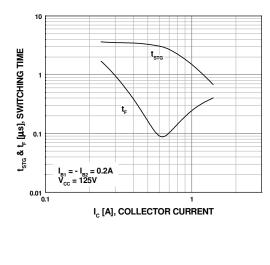
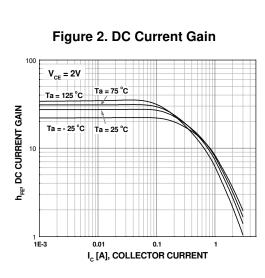


Figure 5. Resistive Load Switching Time







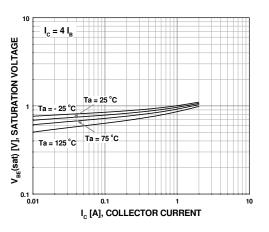
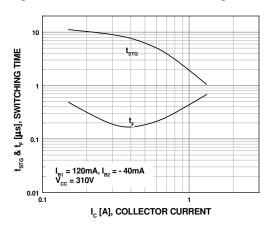
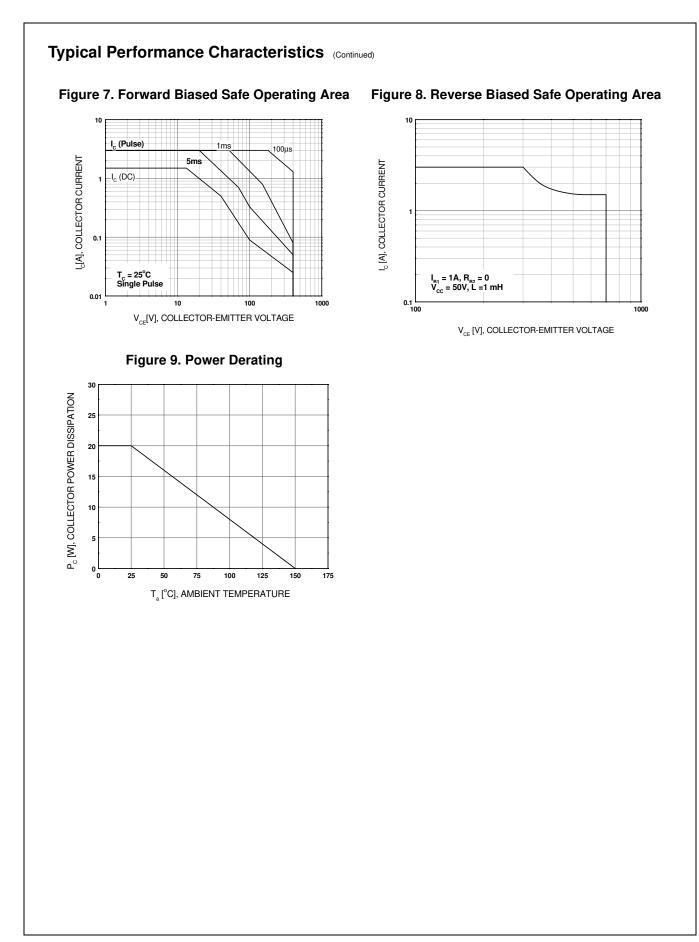
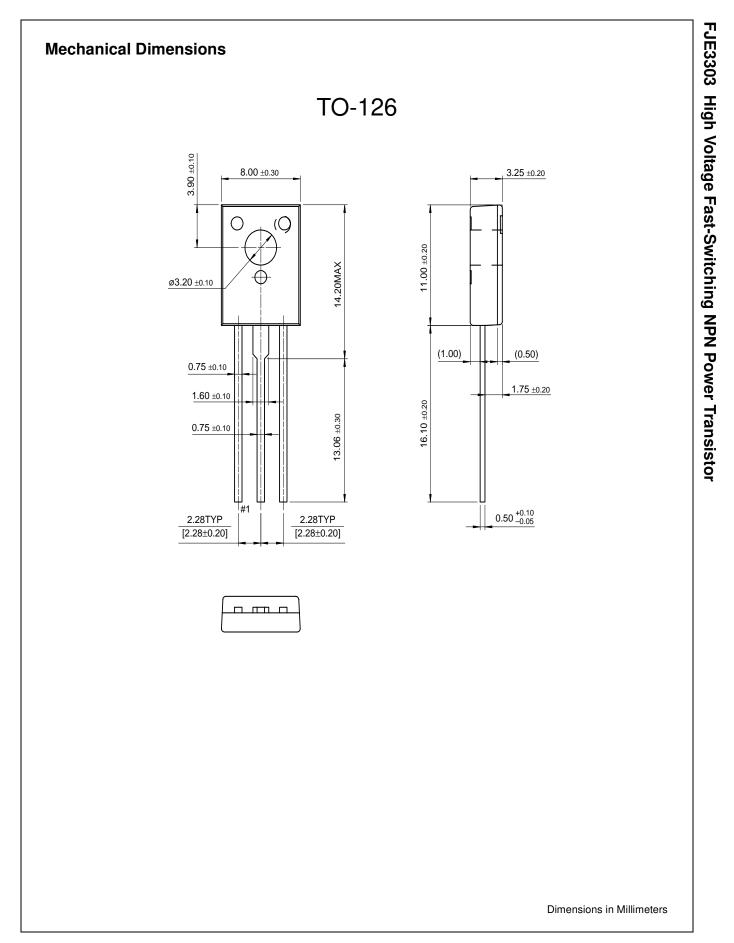


Figure 6. Resistive Load Switching Time







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FJE3303

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Features

- High Voltage Capability
- High Speed Switching
- Suitable for Electronic Ballast and Switching Regulator

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